University of Illinois

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Exam 1

Thursday, Feb. 14, 2013 — 7:00-8:15 PM

Name:				
Section:	9 AM	12 Noon	1 PM	2 PM

Please clearly PRINT your name in CAPITAL LETTERS and CIRCLE YOUR SECTION in the above boxes.

This is a closed book exam and calculators are not allowed. Please show all your work and make sure to include your reasoning for each answer. All answers should include units wherever appropriate.

Problem 1 (25 points)	
Problem 2 (25 points)	
Problem 3 (25 points)	
Problem 4 (25 points)	
TOTAL (100 points)	

- 1. Consider a static volumetric charge density $\rho(x, y, z) = 6\epsilon_0\delta(z) + \rho_s\delta(z-4) \text{ C/m}^3$ in a given region of free space (having permittivity ϵ_0), where the displacement field in the region 0 < z < 4 m is known to be $\mathbf{D} = \hat{x}\epsilon_0 + \hat{z}3\epsilon_0 \text{ C/m}^2$, and $D_z = 2\epsilon_0$ for z > 4 m. Furthermore, field \mathbf{D} is uniform in each of the regions z < 0, 0 < z < 4, and z > 4.
 - a) (3 pts) Determine ρ_s .
 - b) (3 pts) Determine **D** in the region z > 4 m.

c) (4 pts) Determine **D** in the region z < 0.

d) (6 pts) Determine **E** in all three regions (z < 0, 0 < z < 4, and z > 4).

- e) (5 pts) What is the voltage drop from the point (0,0,0) to the point (0,0,4)?
- f) (4 pts) Is the plane at z = 4 m an equipotential surface? Explain.

- 2. An electric field in free space is given as $\mathbf{E} = \hat{x}yz + \hat{y}zx + \hat{z}xy$ V/m.
 - a) (5 pts) Determine if the electric field given above is conservative.

b) (10 pts) Determine the electrostatic potential function, V(x, y, z), corresponding to the field **E** assuming that the potential at the origin is V(0, 0, 0) = 0 V.

c) (5 pts) Determine the total charge contained in a cubic volume $V = 1 \text{ m}^3$ with vertices at (x, y, z) = (0, 0, 0) and (1, 1, 1) m.

d) (5 pts) Determine the charge density ρ in the region corresponding to the electric field.

3. The region between two infinite, plane parallel, perfectly conducting plates at z = 0 and z = 1 m is filled with two slabs of perfect dielectric materials having constant electric permittivities $\epsilon_1 = 2\epsilon_o$ for 0 < z < d m (region 1) and ϵ_2 for d < z < 1 (region 2). The bottom plate is held at constant potential V(0) = 0 and the electrostatic field between the plates is known to be

$$\mathbf{E}(z) = \begin{cases} -\frac{3\epsilon_2}{8\epsilon_0}\hat{z}, \ 0 < z < d \\ -\frac{3\epsilon_1}{8\epsilon_0}\hat{z}, \ d < z < 1 \end{cases} \mathbf{V/m}$$

- a) (4 pts) Verify that the above field satisfies Maxwell's boundary condition regarding **D** at the boundary between the two dielectric slabs.
- b) (7 pts) Write the expression for the electrostatic potential V(z) for 0 < z < 1 m in terms of ϵ_1 , ϵ_2 , and d.

- c) (5 pts) Determine ϵ_2 if the surface charge density on the top plate (at z = 1 m) is $\rho_s = 3\epsilon_o$ C/m².
- d) (3 pts) Does V(z) determined in part (b) satisfy Laplace's equation in the region 0 < z < 1 m? Explain your answer.
- e) (5 pts) What would be the capacitance C of the structure described above if the parallel plates at z = 0 and z = 1 m were constrained to have finite areas $A = W^2$ (where $W \gg 1$ m) facing one another. In this calculation ignore the fringing fields, and express C as a function of ϵ_1 , ϵ_2 , d, and A.

- 4. Consider a co-axial cable of length L that is centered on the origin and lies along the \hat{z} axis. The inner conducting wire has a radius R = 10 mm and carries a surface charge density of $-3\epsilon_0 \text{ C/m}^2$, while the thin, outer conducting shell has a radius 3R = 30 mm and carries a surface charge density of $\epsilon_0 \text{ C/m}^2$. The region between the two conductors is filled with a perfect dielectric material characterized by permittivity $\epsilon = 6\epsilon_0$.
 - a) (8 pts) Assuming that $R \ll L$ (such that fringing fields at the edges of the cable can be neglected), use Gauss' Law in integral form to determine the electric field in the region between the conductors (R < r < 3R) and in the region outside of both conductors (r > 3R).

b) (5 pts) What are the magnitude and unit direction, in Cartesian coordinates, of the displacement field **D** between the conductors at the Cartesian point P = (-15 mm, 20 mm, 10 mm)?

c) (8 pts) Assuming the inner conducting wire is held at a constant potential of $V_R = 10$ mV, what is the electrostatic potential V_{3R} on the outer conducting shell? **Hint**: there are two independent ways of solving for V_{3R} .

- d) (4 pts) If the dielectric material between the conductors is not perfect, such that $\sigma \neq 0$, indicate whether the following statements are true or false:
 - i. **TRUE/FALSE:** Free electrons inside the material will be accelerated toward the inner conductor via the Lorentz force.
 - ii. **TRUE/FALSE:** Current will flow in the $+\hat{r}$ direction.
 - iii. TRUE/FALSE: The surface charge density on the outer conductor will decrease initially.
 - iv. TRUE/FALSE: The capacitance of the system will decrease initially.

6. Consider a static volumetric charge density $\rho(x; y; z) = 6\varepsilon_o \ \delta(z) + \rho_s(z - 4) \ C/m^3$ in a given region of free space (having permittivity ε_o), where the displacement field in the region 0 < z < 4 m is known to be $\mathbf{D} = \hat{x}\varepsilon_o + \hat{z}3\varepsilon_o \ C/m^2$ for and $D_z = 2\varepsilon_o \ C/m^2$ for z > 4 m. Furthermore, field \mathbf{D} is uniform in each of regions z < 0, 0 < z < 4 m, and z > 4 m.

- a) Determine ρ_s .
- b) Determine **D** for the region z > 4 m.
- c) Determine **D** for the region z < 0.
- d) Determine **E** in all three regions (z < 0, 0 < z < 4, and z > 4).
- e) What is the voltage drop from the point (0,0,0) and the point (0,0,4)?
- f) Is the plane at z=4 m an equi-potential surface? Explain.

Solutions

6. Consider a static charge density $\rho \rho(x; y; z) = 6\varepsilon_o \delta(z) + \rho_s(z - 4) \text{ C/m}^3$ in a given region of free space (having permittivity ε_o), where the displacement field is known to be $\mathbf{D} = \hat{x}\varepsilon_o + \hat{z}3\varepsilon_o \text{ C/m}^2$ for 0 < z < 4 m and $D_z = 2\varepsilon_o \text{ C/m}^2$ in the region z > 4 m. The volume charge density corresponds to two infinite surfaces at z = 0m and z = 4m with surface charges of 6C/m³ and $\rho_s \text{ C/m}^3$, respectively.

a) Apply boundary conditions at the interface: $\rho = \hat{n} \cdot [\mathbf{D}_1 - \mathbf{D}_2] \text{At } z = 4\text{m}$, we have that the surface charge density ρ_s must be equal to the difference between the normal components of **D** on each side of the interface. Then, with $\hat{n} = \hat{z}$, we have:

$$\rho_s = D_z \big|_{z=4^+} - D_z \big|_{z=4^-} = 2\varepsilon_o - 3\varepsilon_o = -\varepsilon_o \frac{C}{m^2}$$

b) In the region z > 4m, we know that $D_z = 2\varepsilon_o C/m^2$. In addition, since the tangential components of **E** at the interface at z = 4m must be continuous, i.e., $E_x|_{z=4^+} = E_x|_{z=4^-}$, and assuming that the charged sheets are in a vacuum, we can verify that $D_x|_{z=4^+} = D_x|_{z=4^-} = \varepsilon_o C/m^2$. Extending the field to the region z > 4 m, we find that

$$\mathbf{D} = \varepsilon_o \hat{x} + 2\varepsilon_o \hat{z} \frac{\mathbf{C}}{\mathbf{m}^2} \text{ for } z > 4 \text{ m.}$$

c) Applying boundary conditions at the interface at z = 0 m, we have that $D_z|_{z=0^+} - D_z|_{z=0^-} = 6$ thus, $D_z|_{z=0^-} = 3\varepsilon_o - 6\varepsilon_o = -3\varepsilon_o \text{C/m}^2$. In addition, since $E_x|_{z=0^+} = E_x|_{z=0^-}$ and given that the space is a vacuum, we can verify that $D_x|_{z=0^-} = D_x|_{z=0^+} = \varepsilon_o$. Extending the fields to the region z < 0 m, we find that

$$\mathbf{D} = \varepsilon_o \hat{x} - 3\varepsilon_o \hat{z} \frac{C}{m^2} \text{ for } z < 0 \text{ m.C}$$

d) The displacement field, **D**, is defined to be equal to ε_{medium} **E**. Since the region is in free space $\varepsilon_{medium} = \varepsilon_0$. The electric field in the region where z < 0 m is

$$\mathbf{E} = \frac{\mathbf{D}}{\varepsilon_o} = \frac{\varepsilon_o \hat{x} + (3\varepsilon_o - 6)\hat{z}}{\varepsilon_o} = \hat{x} - 3\hat{z}\frac{\mathbf{V}}{\mathbf{m}}$$

The electric field in the region from z = 0m to z = 4m is

$$\mathbf{E} = \frac{\mathbf{D}}{\varepsilon_o} = \frac{\varepsilon_o \hat{x} + 3\varepsilon_o \hat{z}}{\varepsilon_o} = \hat{x} + 3\hat{z} \frac{\mathbf{V}}{\mathbf{m}}$$

The electric field in the region where z > 4m is

$$\mathbf{E} = \frac{\mathbf{D}}{\varepsilon_o} = \frac{\varepsilon_o \hat{x} + 2\varepsilon_o \hat{z}}{\varepsilon_o} = \hat{x} + 2\hat{z} \frac{\mathbf{V}}{\mathbf{m}}$$

e) We can calculate the voltage drop from (0,0,0) m to (0,0,4) with the following equation

$$\Delta V = V_{(0,0,4)} - V_{(0,0,4)} = -\int_{0}^{4} \mathbf{E} \cdot \mathbf{dl} = -\int_{0}^{4} \frac{\mathbf{D}}{\varepsilon_{o}} \cdot \mathbf{dl}$$
$$= -\int_{0}^{4} (\hat{x} + 3\hat{z}) \cdot \hat{z} dz = -3z \Big|_{0}^{4} = -12 V$$

f) The plane at z=4 m is NOT an equipotential surface. Because of the x-component of the electric field, integration on the top plane in the horizontal direction gives a non-zero result indicating a potential drop on the surface.

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